



SiC SCHOTTKY DIODE TYPE 2x200A

Features

Preliminary

- High surge current capable
- Zero reverse recovery current
- High bandwidth
- Temperature Independent Switching Behavior
- VDC 1200 V
- I_F ($T_C < 135^\circ\text{C}$) 2x200 A

Benefits

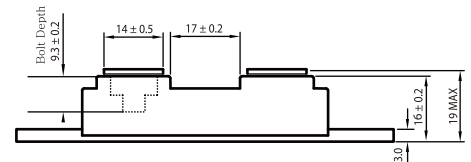
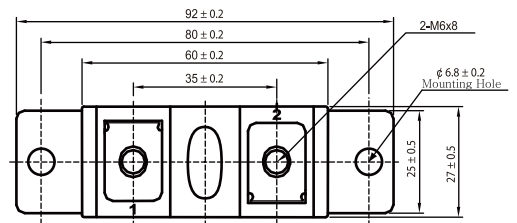
- Unipolar rectifier
- Zero switching loss
- Higher efficiency
- Smaller heat sink
- Parallel devices without thermal runaway

Applications

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters
- Welding equipment
- Power factor correction
- Diode snubber
- Automotive
- induction heating



Dimensions in mm (1 mm = 0.0394")



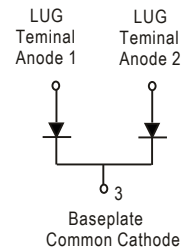
Maximum Ratings

Operating Junction Temperature : - 55 °C to +175 °C

Storage Temperature : -55 °C to +175 °C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
DACSB400120CT	1200V	1200V

Maximum Rating	Symbol	Conditions	Value	Unit
Continuous forward current (per leg)	I_F	$T_C = 135^\circ\text{C}$	200	A
Surge non-repetitive forward current sine halfwave (per leg)	I_{FSM}	$T_C = 25^\circ\text{C}$, $t_p = 8.3\text{ ms}$	1600	
		$T_C = 150^\circ\text{C}$, $t_p = 8.3\text{ ms}$	1000	
Non-repetitive peak forward current (per leg)	$I_{F,max}$	$T_C = 25^\circ\text{C}$, $t_p = 10\ \mu\text{s}$	6400	
		$T_C = 150^\circ\text{C}$, $t_p = 10\ \mu\text{s}$	4000	
Repetitive peak reverse voltage	V_{RRM}	$T_J = 25^\circ\text{C}$	1200	V
Mounting torque		M6 Screw	3~4.7	N-m





Electrical Characteristics, at Tj=25 °C, unless otherwise specified. (per leg)

Static Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
DC blocking voltage	V _{DC}		1,200	-	-	V
Diode forward voltage	V _F	I _F =200A, T _j =25 °C	-	1.6	1.8	
		I _F =200A, T _j =175 °C	-	2.4	2.9	
Reverse current	I _R	V _R =1,200V, T _j =25 °C	-	10	130	μA
		V _R =1,200V, T _j =175 °C	-	140	1,400	

AC Characteristics (per leg)

Static Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
Total capacitive charge	Q _{rr}	V _R =1,200V, T _j =25 °C	-	617	-	nC
Total capacitance	C	V _R =0V, f=1 MHz T _j =25 °C	-	11,120	-	pF
		V _R =600V, f=1 MHz T _j =25 °C	-	1,104	-	
		V _R =1,000V, f=1 MHz T _j =25 °C	-	1,034	-	

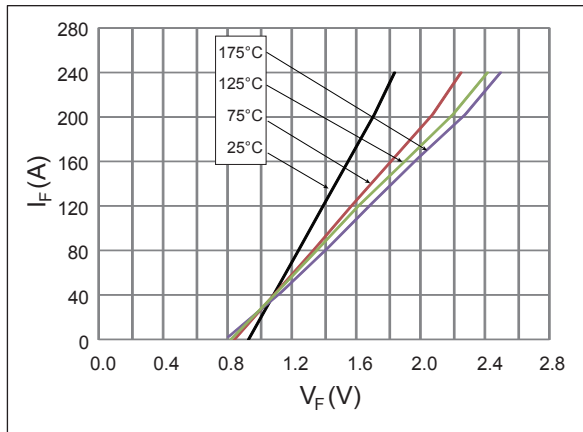
Thermal Characteristics (per leg)

Static Characteristics	Symbol	Values	Unit
		typ.	
Thermal resistance from junction to case	R _{θJC}	0.07	°C/W

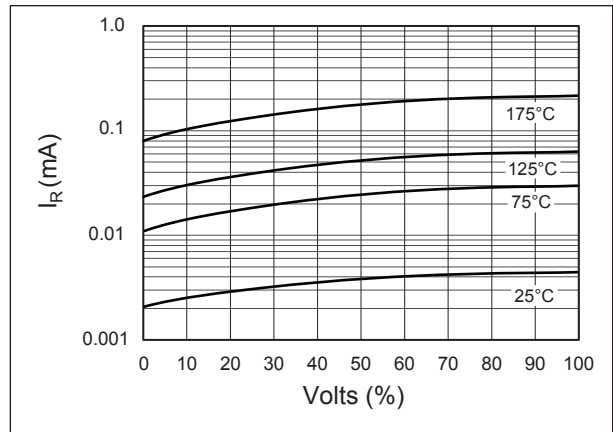


Typical Performance

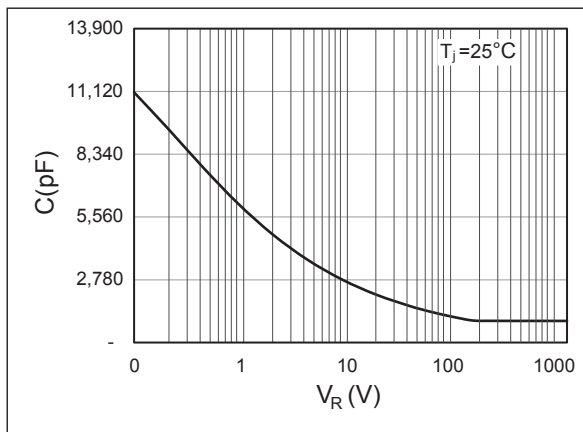
Forward Characteristics (parameterized on T_j)



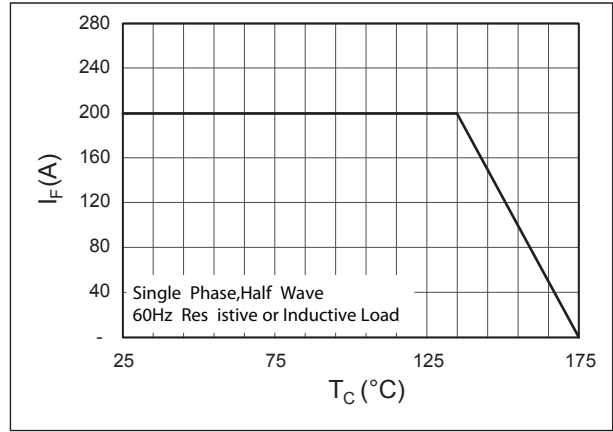
Reverse Characteristics (parameterized on T_j)



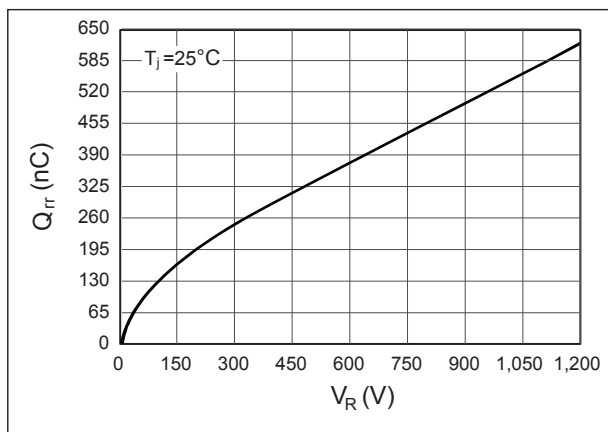
Capacitance



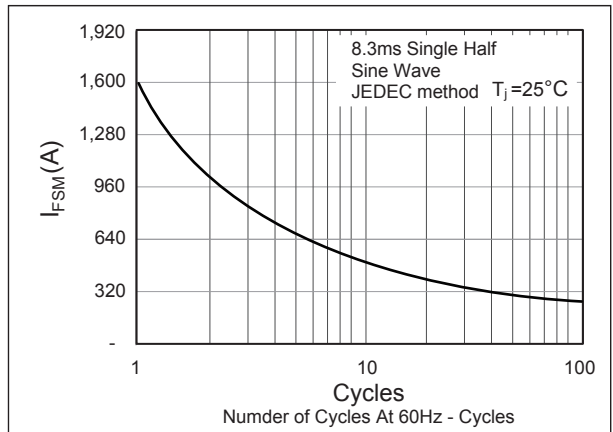
Current Derating



Recovery Charge



Forward Surge Current





Disclaimer

DACO Semiconductor reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein.

DACO Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does DACO Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

Purchasers is responsible for its products and applications using DACO Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by DACO Semiconductor. "Typical" parameters which may be provided in DACO Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts.

DACO Semiconductor products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of DACO Semiconductor's product can reasonably be expected to result in personal injury, death or severe property or environmental damage. DACO Semiconductor accept no liability for inclusion and/or use of DACO Semiconductor's products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Purchasers buy or use DACO Semiconductor products for any such unintended or unauthorized application, Purchasers shall indemnify and hold DACO Semiconductor and its suppliers and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that DACO Semiconductor was negligent regarding the design or manufacture of the part.

No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of DACO Semiconductor Co., Ltd.